Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

3. Applications

- · High-side load switch
- Battery management
- DC-to-DC conversion
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-13.7	Α
Static characte	eristics			·	·		
R _{DSon}	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -8.1 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	14.4	18	mΩ
	resistance	$V_{GS} = -2.5 \text{ V}; I_D = -6.3 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	22.5	30	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source		
3	S	source		D
4	G	gate]	
5	D	drain		
6	D	drain	المممكا	\$ 017aaa257
7	D	drain	8 7 6 5	
8	D	drain	MLPAK33 (SOT8002-1)	

6. Ordering information

Table 3. Ordering information

Type number Package						
	Name	Description	Version			
PXP018-20QX		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1			

7. Marking

Table 4. Marking codes

Type number	Marking code
PXP018-20QX	8АН

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-13.7	Α
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-8.4	Α
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-5.1	Α
		V _{GS} = -4.5 V; T _{sp} = 25 °C		-	-39.7	Α
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-55.4	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; t ≤ 5 s	[1]	-	4.8	W
		T _{amb} = 25 °C	[1]	-	1.7	W
		T _{sp} = 25 °C		-	40	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode		•			
Is	source current	T _{amb} = 25 °C	[1]	-	-1.7	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

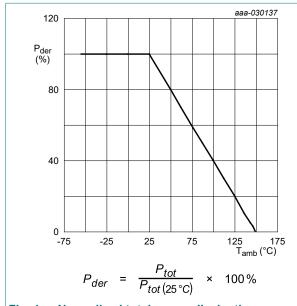


Fig. 1. Normalized total power dissipation as a function of ambient temperature

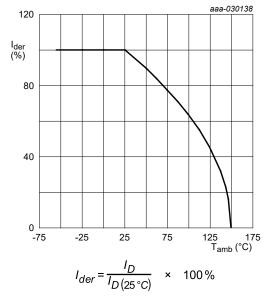


Fig. 2. Normalized continuous drain current as a function of ambient temperature

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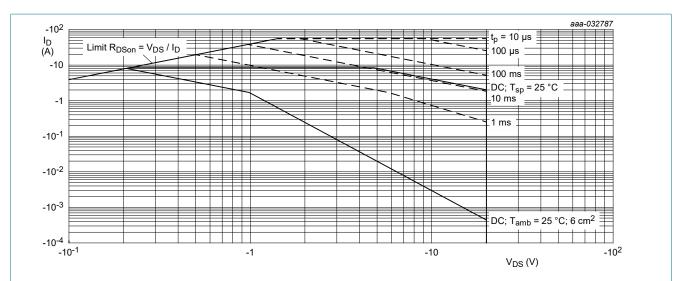


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uiu-a)	thermal resistance from	in free air	[1]	-	150	190	K/W
	junction to ambient		[2]	-	60	75	K/W
		in free air; t ≤ 5 s	[2]	-	21	26	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	2.1	3.1	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

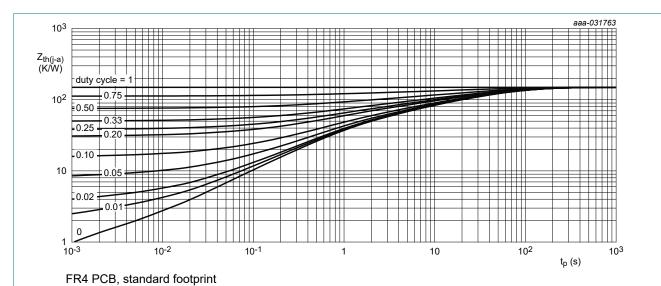


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

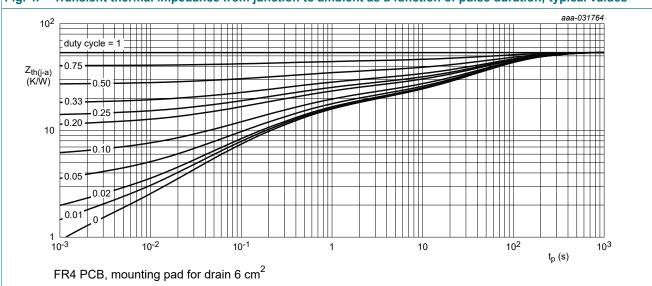


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-0.7	-0.9	-1.25	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -8.1 \text{ A}; T_j = 25 \text{ °C}$	-	14.4	18	mΩ
	resistance	V_{GS} = -4.5 V; I_D = -8.1 A; T_j = 150 °C	-	20.4	25.6	mΩ
		V_{GS} = -2.5 V; I_D = -6.3 A; T_j = 25 °C	-	22.5	30	mΩ
g _{fs}	forward transconductance	V_{DS} = -10 V; I_D = -8.1 A; T_j = 25 °C	-	23.2	-	S
R_{G}	gate resistance	f = 1 MHz	-	4.6	-	Ω
Dynamic ch	aracteristics		ı		<u> </u>	
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -8.1 A; V _{GS} = -4.5 V;	-	23.2	34.8	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	4.1	-	nC
Q _{GS(th)}	pre-threshold gate- source charge		-	2.1	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	2	-	nC
Q _{GD}	gate-drain charge		-	7.1	-	nC
V_{GSpl}	gate-source plateau voltage	$V_{DS} = -10 \text{ V}; I_D = -8.1 \text{ A}; T_j = 25 \text{ °C}$	-	-1.8	-	V
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	2360	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	310	-	pF
C _{rss}	reverse transfer capacitance		-	280	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -10 \text{ V}; I_D = -6.3 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	7	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	22	-	ns
t _{d(off)}	turn-off delay time]	-	50	-	ns
t _f	fall time	1	-	30	-	ns
Source-drai	n diode		1		-	
V _{SD}	source-drain voltage	$I_S = -1.7 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	I _S = -1.7 A; dI _S /dt = 100 A/μs;	-	23	-	ns
Q _r	recovered charge	$V_{GS} = -4.5 \text{ V}; V_{DS} = -10 \text{ V}; T_j = 25 \text{ °C}$	-	10	-	nC
t _a	reverse recovery rise time		-	9	-	ns
t _b	reverse recovery fall time	1	-	14	-	ns

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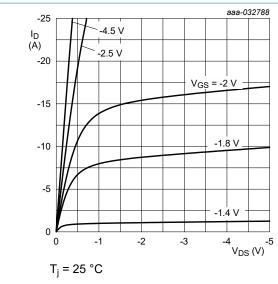


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

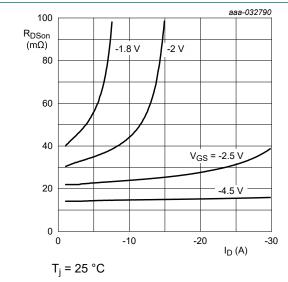


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

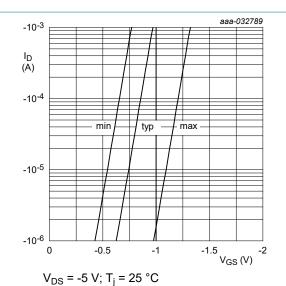


Fig. 7. Sub-threshold drain current as a function of

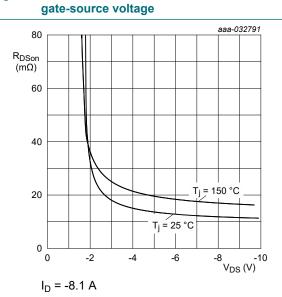


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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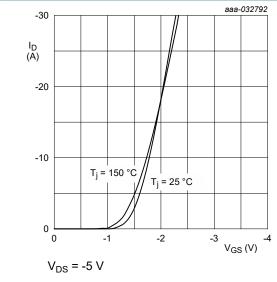


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

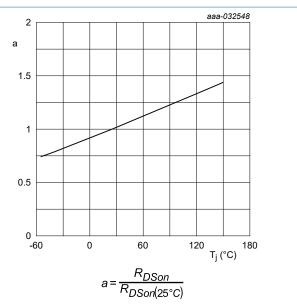


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

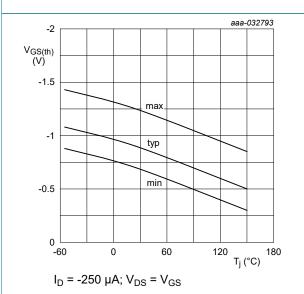


Fig. 12. Gate-source threshold voltage as a function of junction temperature

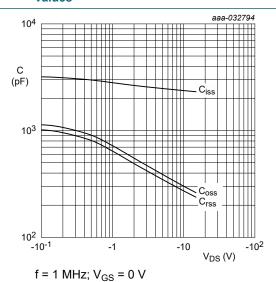


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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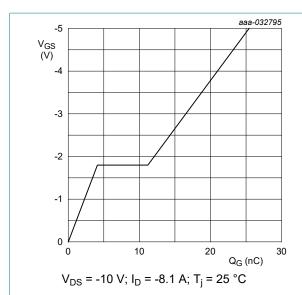


Fig. 14. Gate-source voltage as a function of gate charge; typical values

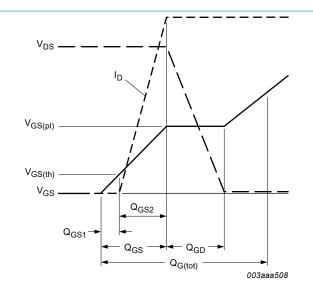


Fig. 15. Gate charge waveform definitions

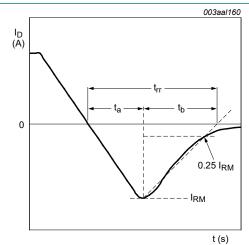


Fig. 16. Reverse recovery timing definition

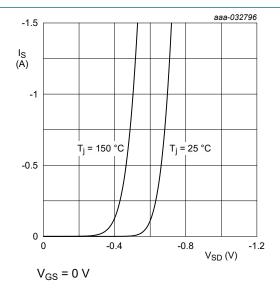
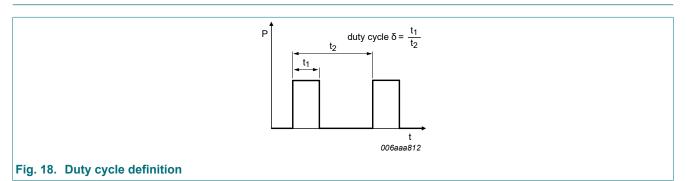


Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information



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12. Package outline

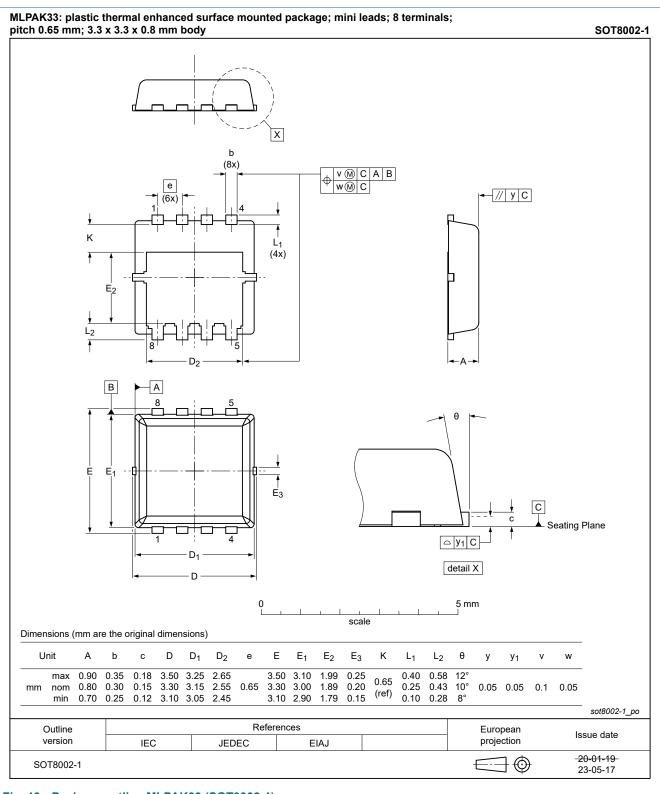
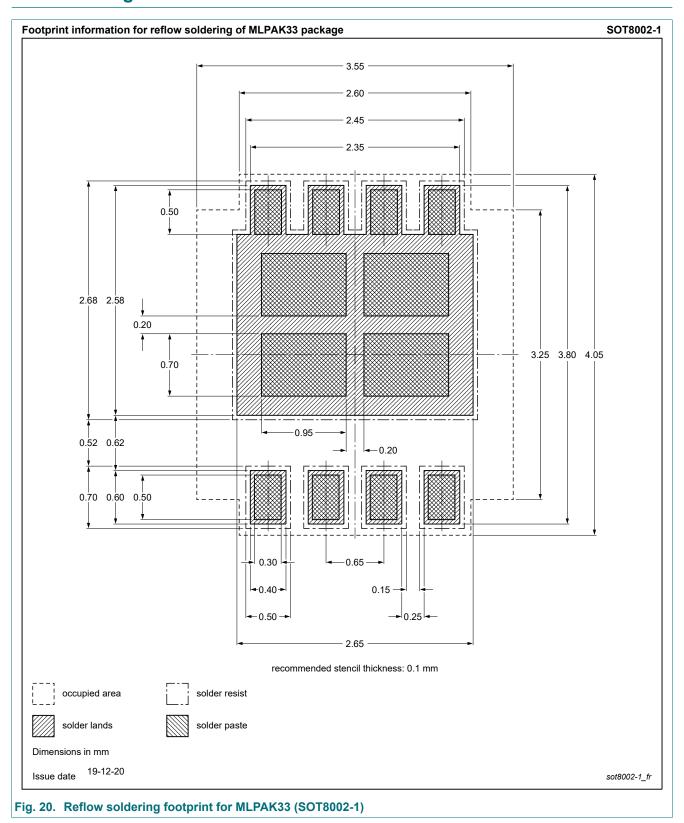


Fig. 19. Package outline MLPAK33 (SOT8002-1)

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13. Soldering



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14. Revision history

Table 8. Revision history

table of Noviolon motory								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PXP018-20QX v.3	20230731	Product data sheet	-	PXP018-20QX v.2				
Modifications:	Chapter "Package or	Chapter "Package outline": drawing update						
PXP018-20QX v.2	20211026	Product data sheet	-	PXP018-20QX v.1				
PXP018-20QX v.1	20210105	Product data sheet	-	-				

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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PXP018-20QX

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